

# isc N-Channel MOSFET Transistor

FDD86369

### **FEATURES**

- Drain Current : I<sub>D</sub>= 90A@ T<sub>C</sub>=25 ℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 80V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 7.9 \text{m} \Omega \text{ (Max)} @ V_{GS} = 10 \text{V}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **DESCRIPTION**

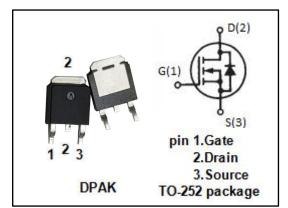
 motor drive, DC-DC converter, power switch and solenoid drive.

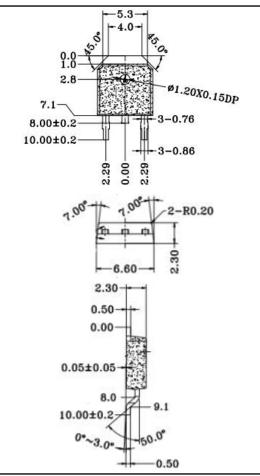
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	80	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
I <sub>D</sub>	Drain Current-Continuous	90	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	150	W
TJ	Max. Operating Junction Temperature -55~175		$^{\circ}$
T <sub>stg</sub>	Storage Temperature -55~175		$^{\circ}$

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.0	°C/W





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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	80		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 0.25mA	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 40A		7.9	m Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±0.1	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0		1.0	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 40A; V <sub>GS</sub> = 0		1.25	V

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